



Successful SIS multilayer activities on cavities and samples using ALD

Marc Wenskat on behalf of our SRF R&D Team

SIS multilayers (PE)-ALD investigation at UHH

Thermal ALD: Al_2O_3

Capability for
coating
single-cell cavities



PEALD: AlN, NbTiN, NbN

Capability for
coating
planar samples



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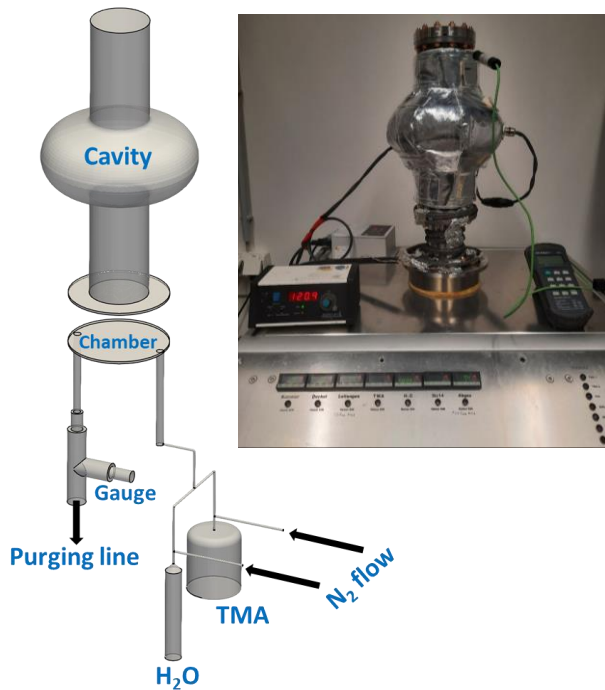


Successful Al_2O_3 coating of high-gradient 1.3 GHz cavities by thermal ALD

✓ Proof-of-principle experiment

- Process optimization
- Thermal ALD Process Simulation

Thermal ALD setup



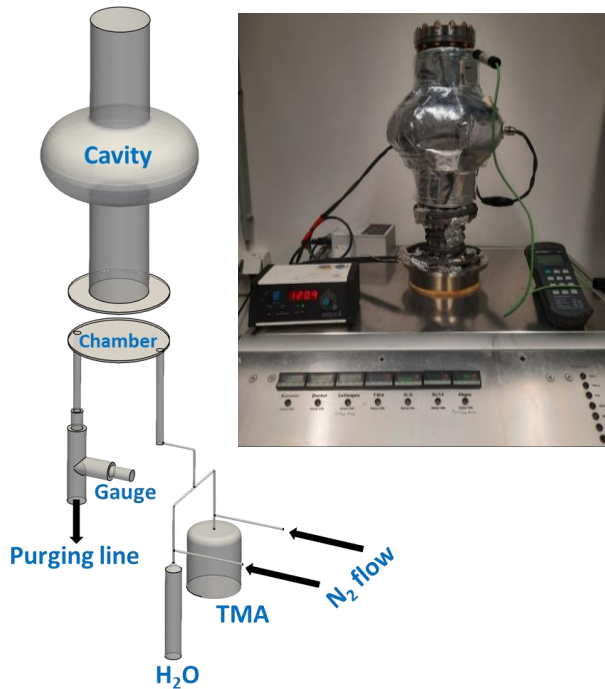
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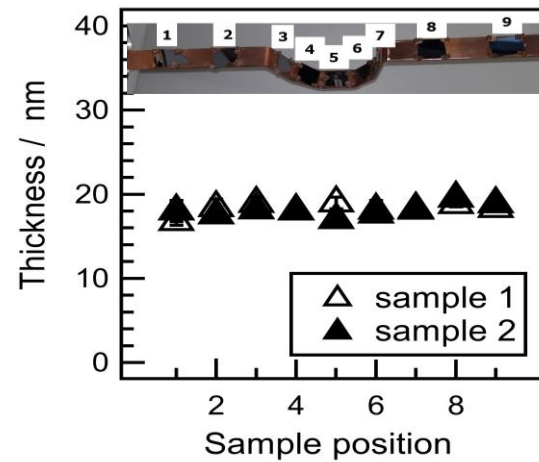
✓ Several single-cell cavities successfully coated

Thermal ALD setup



Process optimization

Precursors TMA/ H_2O
Temp. 120 °C
Thickness ~18 nm



Successful Al₂O₃ coating of high-gradient 1.3 GHz cavities by thermal ALD

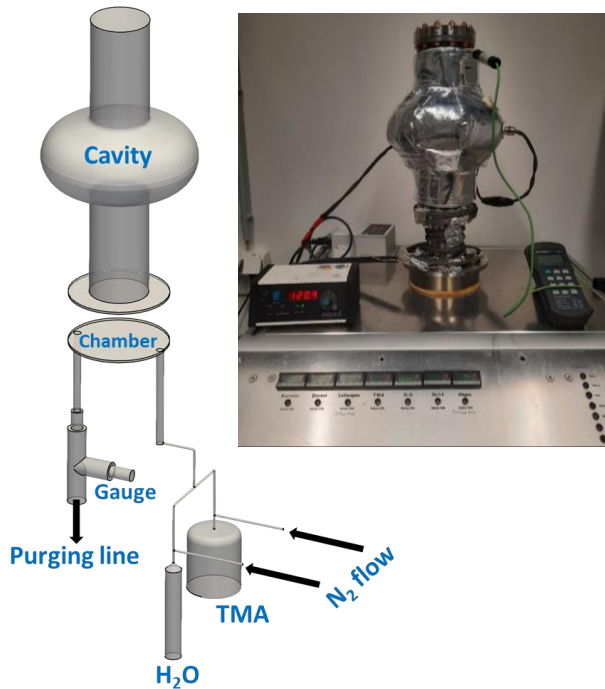
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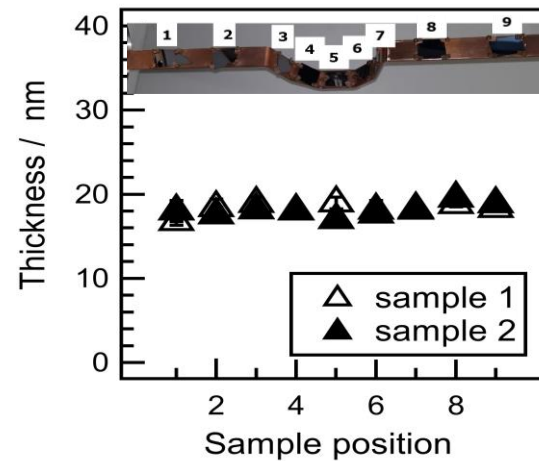
✓ Gradients above 40MV/m without any deterioration in Q-value

Thermal ALD setup

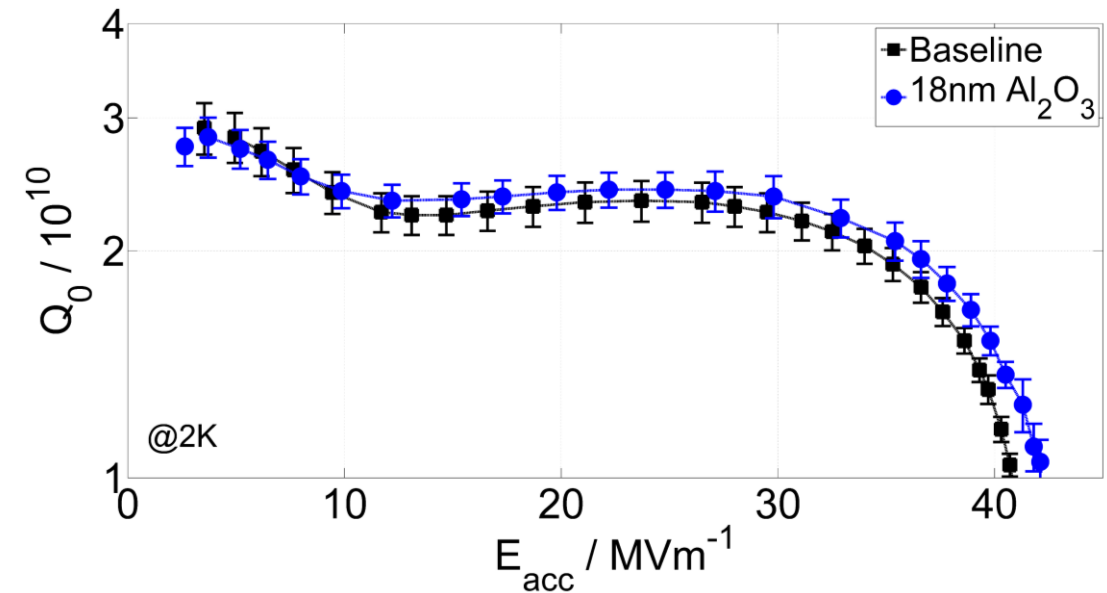


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Cavity performance



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DOI 10.1088/1361-6668/aca83f

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Thermal ALD: Al_2O_3

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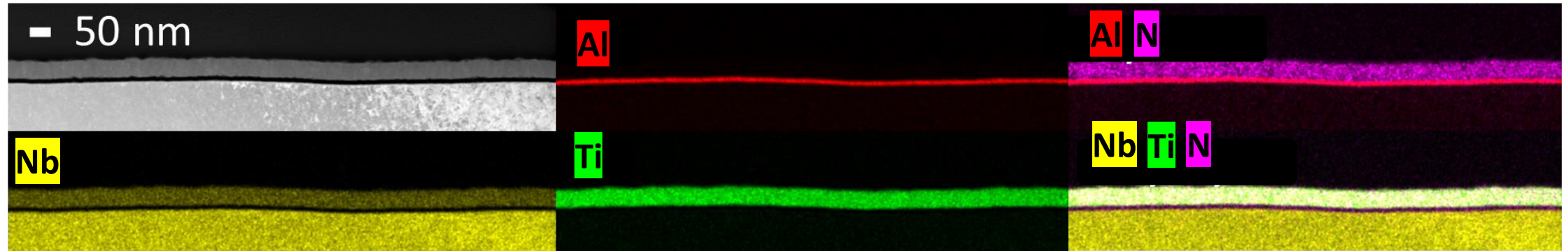
PEALD: AlN , NbTiN , NbN

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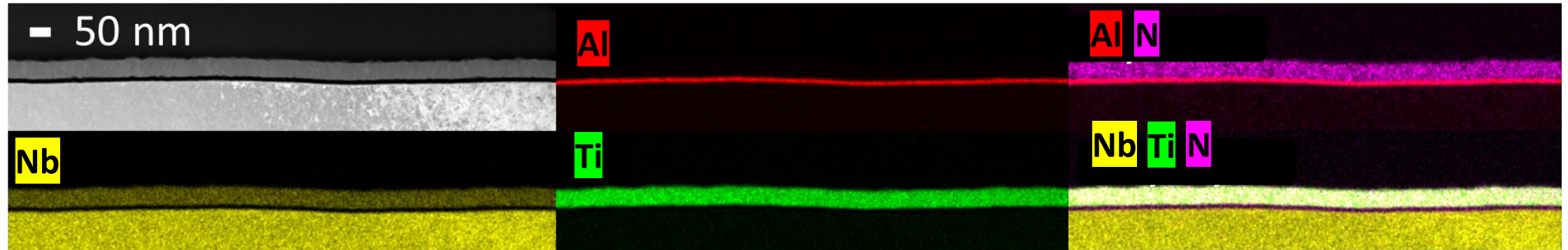
Tailored AlN-NbTiN multilayers deposited by PEALD on Nb and Si substrates

➤ Elemental analysis

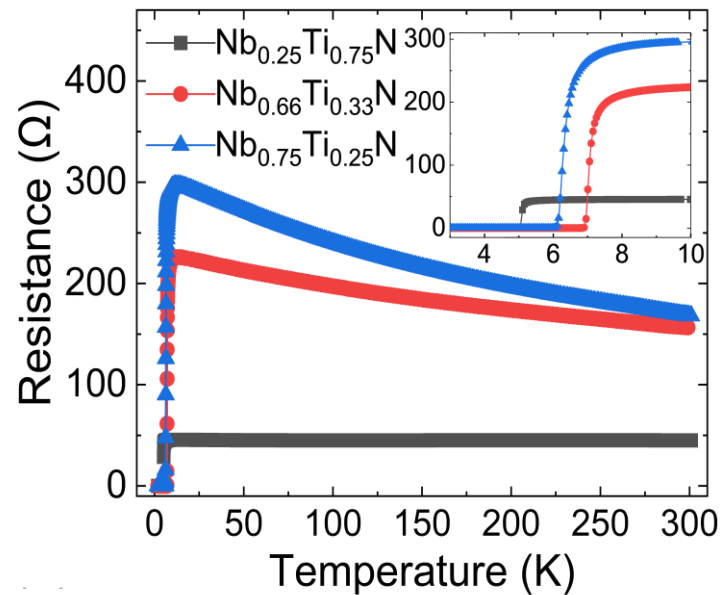


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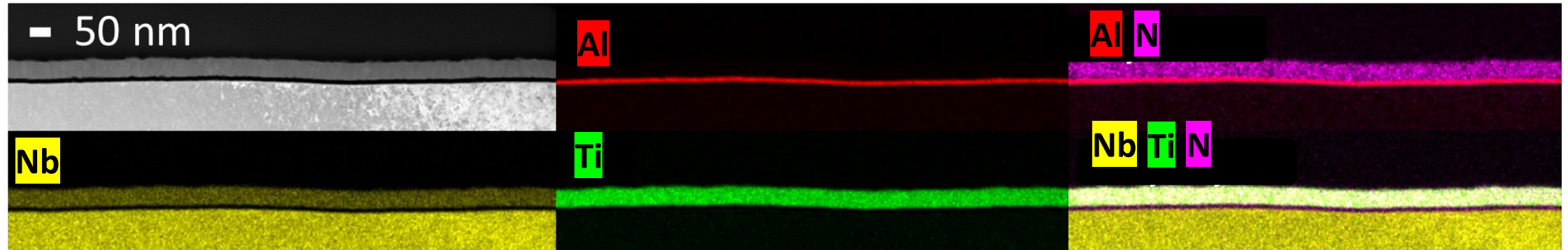


➤ Superconducting $\text{Nb}_x\text{Ti}_{1-x}\text{N}$ film composition

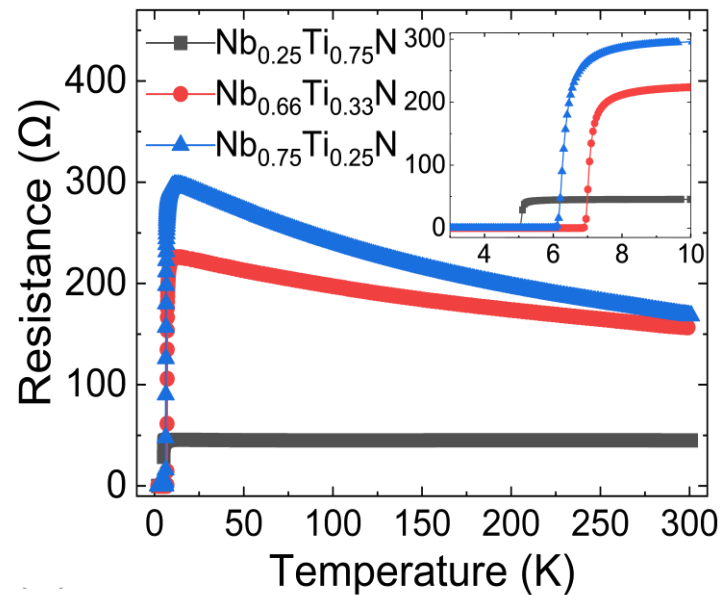


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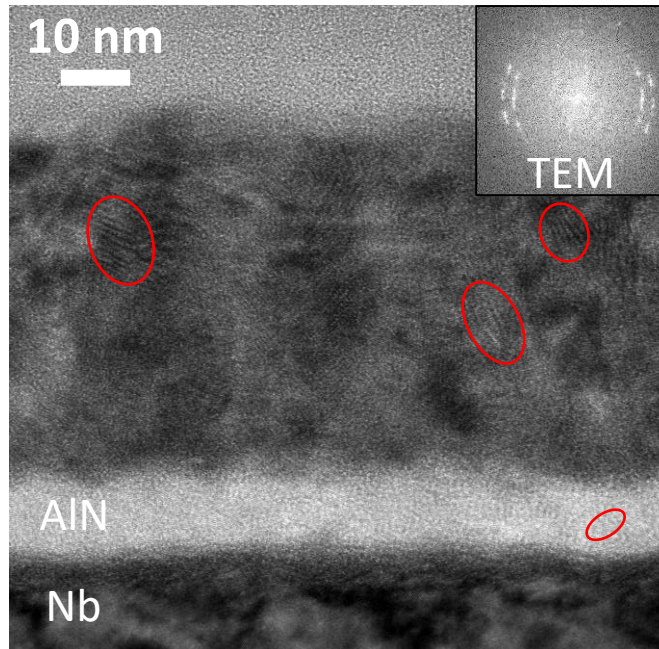
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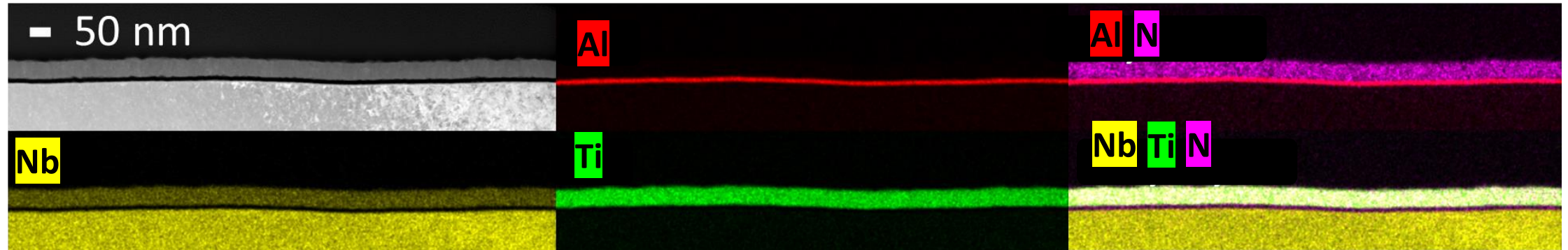


➤ Crystallinity

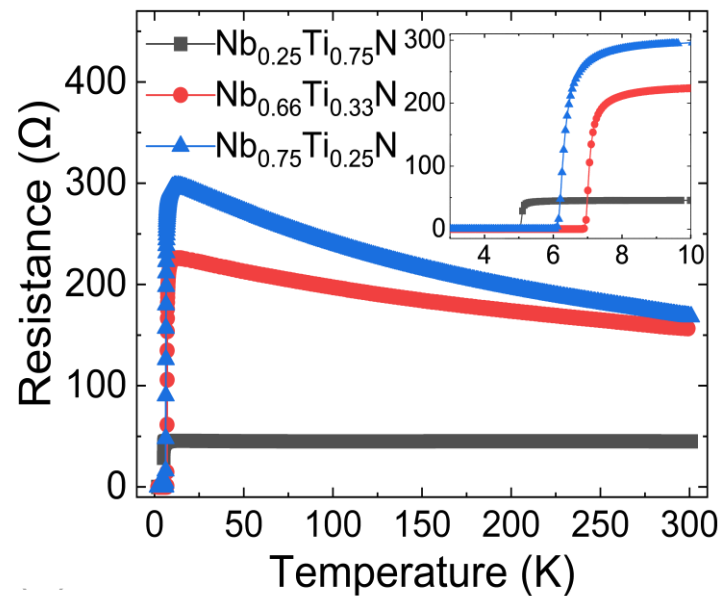


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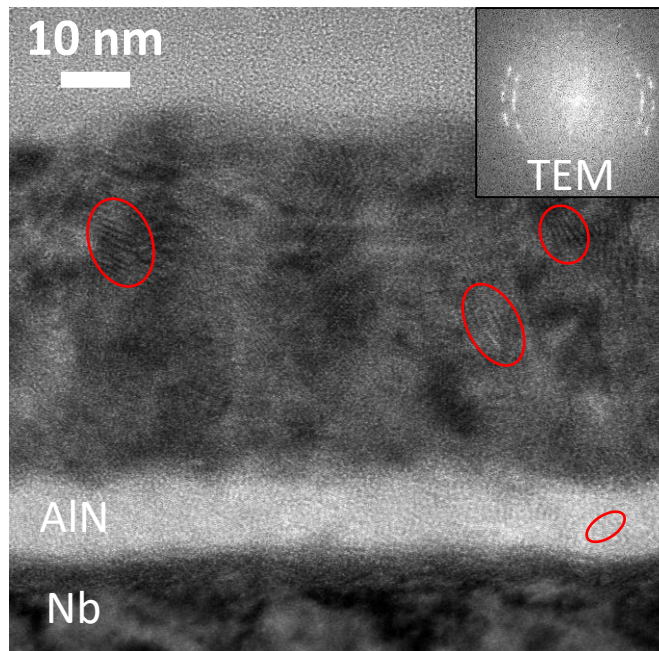
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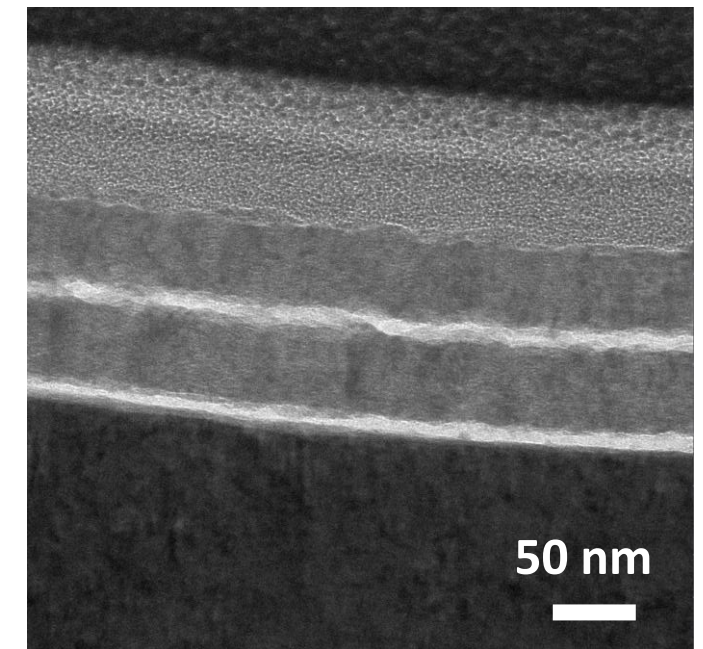
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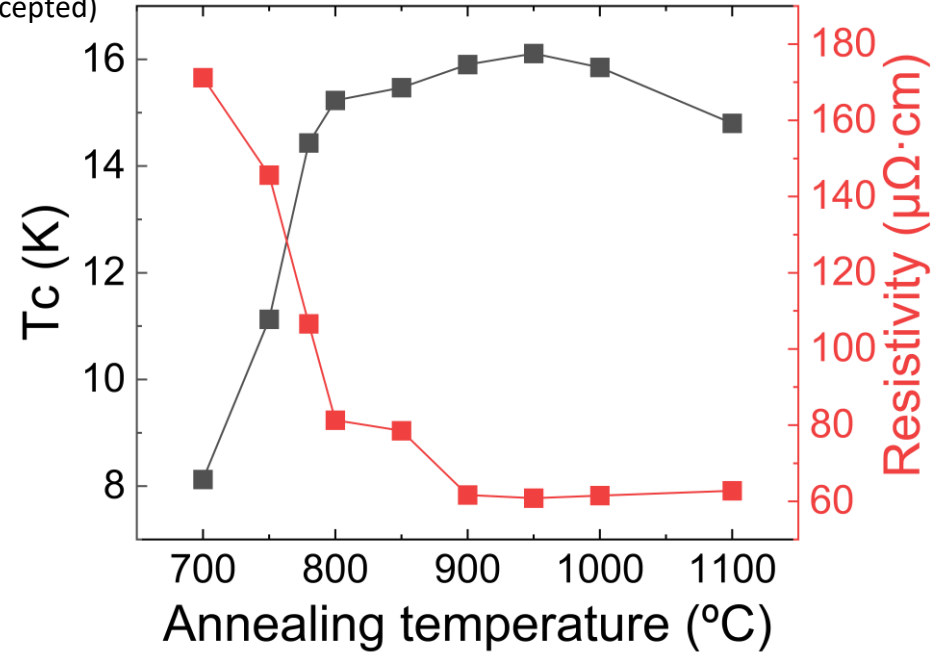
➤ Nb – (AlN – NbTiN) x2



AlN-NbTiN multilayers by PEALD are ready to move on to cavities

➤ Enhancement superconducting properties annealing

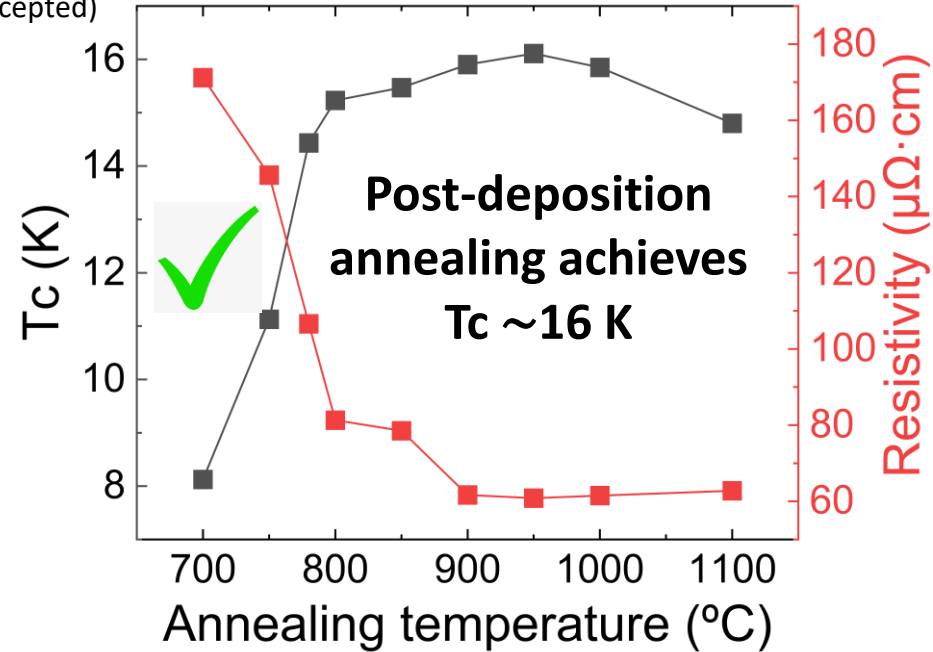
AlN-NbTiN multilayers Detailed info: I. González Díaz-Palacio *et al.*,
Thermal annealing of superconducting niobium titanium nitride thin films
deposited by plasma-enhanced atomic layer deposition *Journal of Applied Physics*
(accepted)



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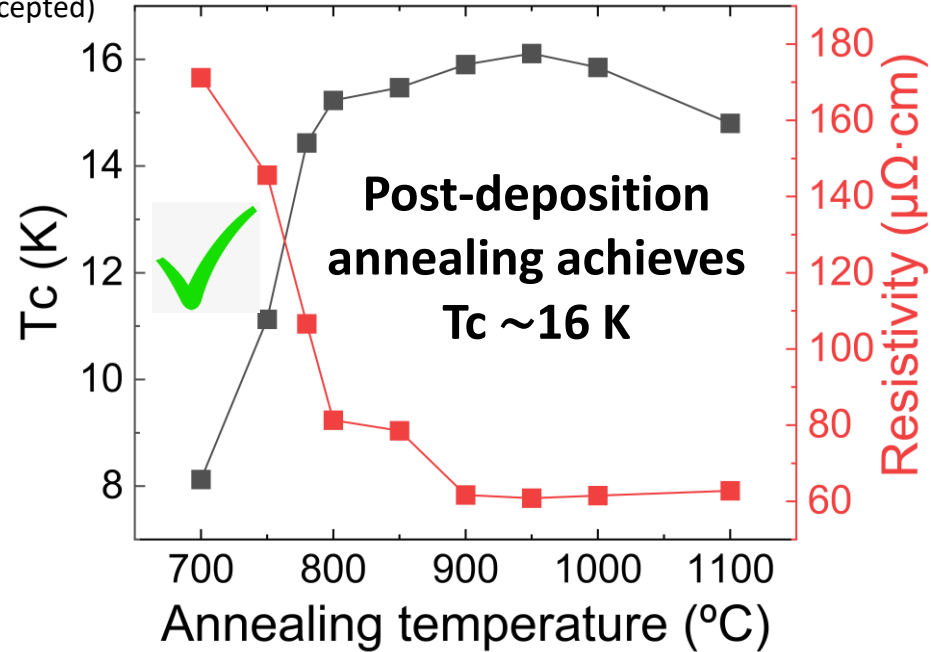
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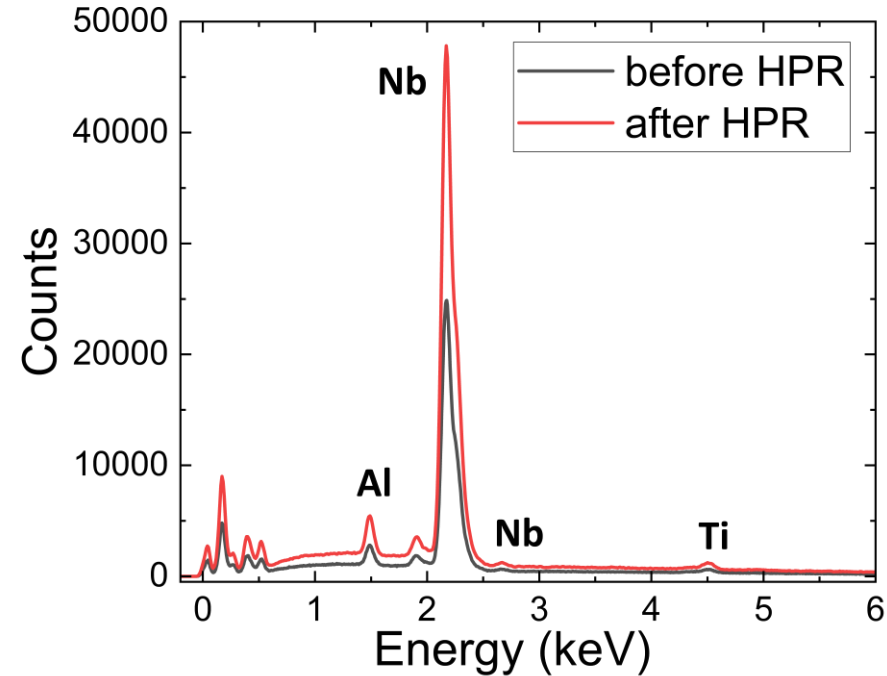
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- Success AlN-NbTiN multilayers to cavity preparation techniques: high pressure rinsing (HPR)



DESY facilities
Cleanroom ISO4

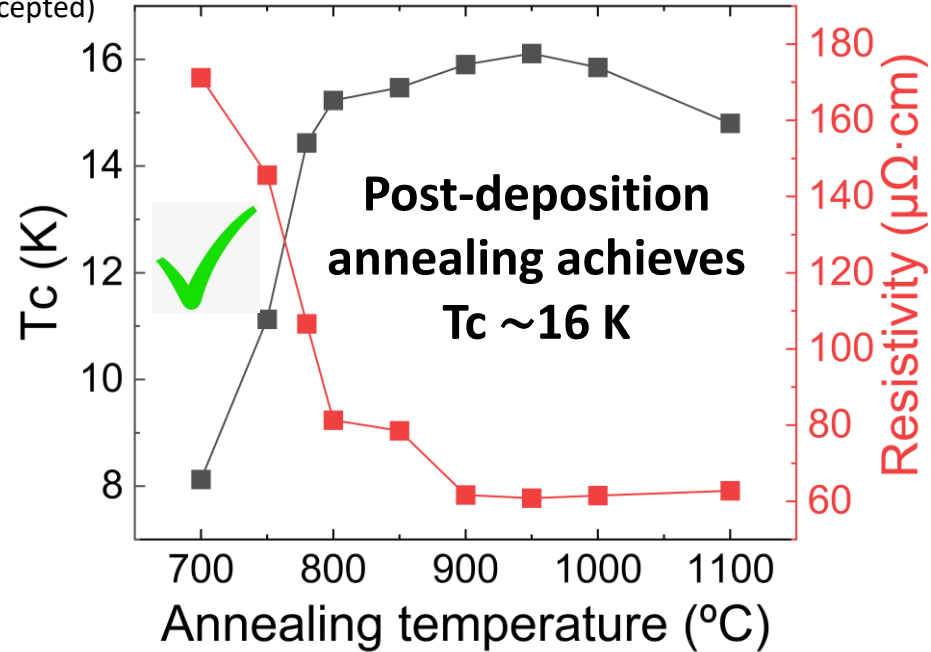


Layers deposited by (PE)-ALD
survive 7 HPR

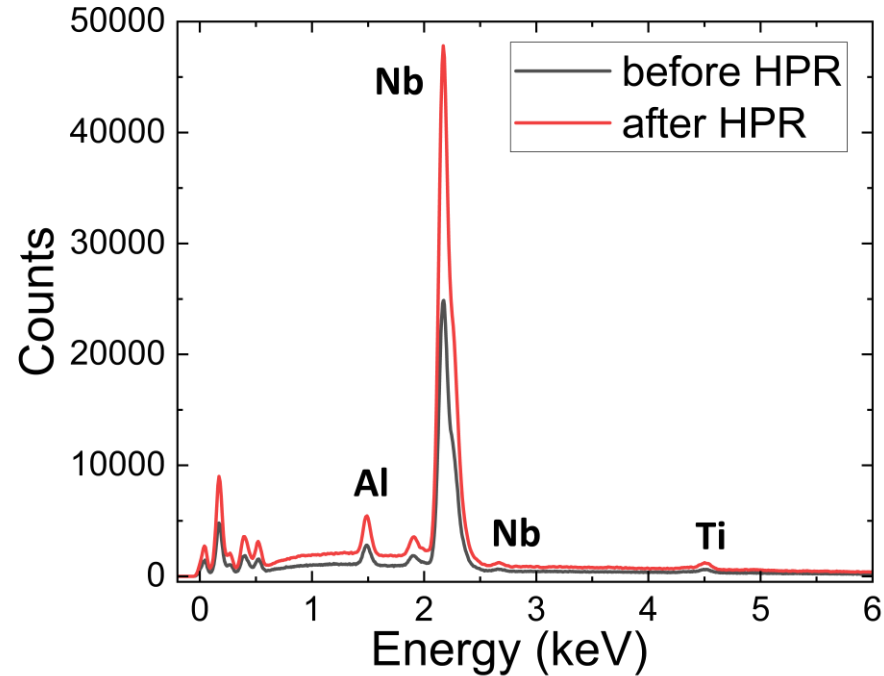
AlN-NbTiN multilayers by PEALD are ready to move on to cavities

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- Success AlN-NbTiN multilayers to cavity preparation techniques: high pressure rinsing (HPR)



DESY facilities
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- Field emission from planar films threshold voltage of:



Annealed: 281 MV/m
As-deposited: 95 MV/m

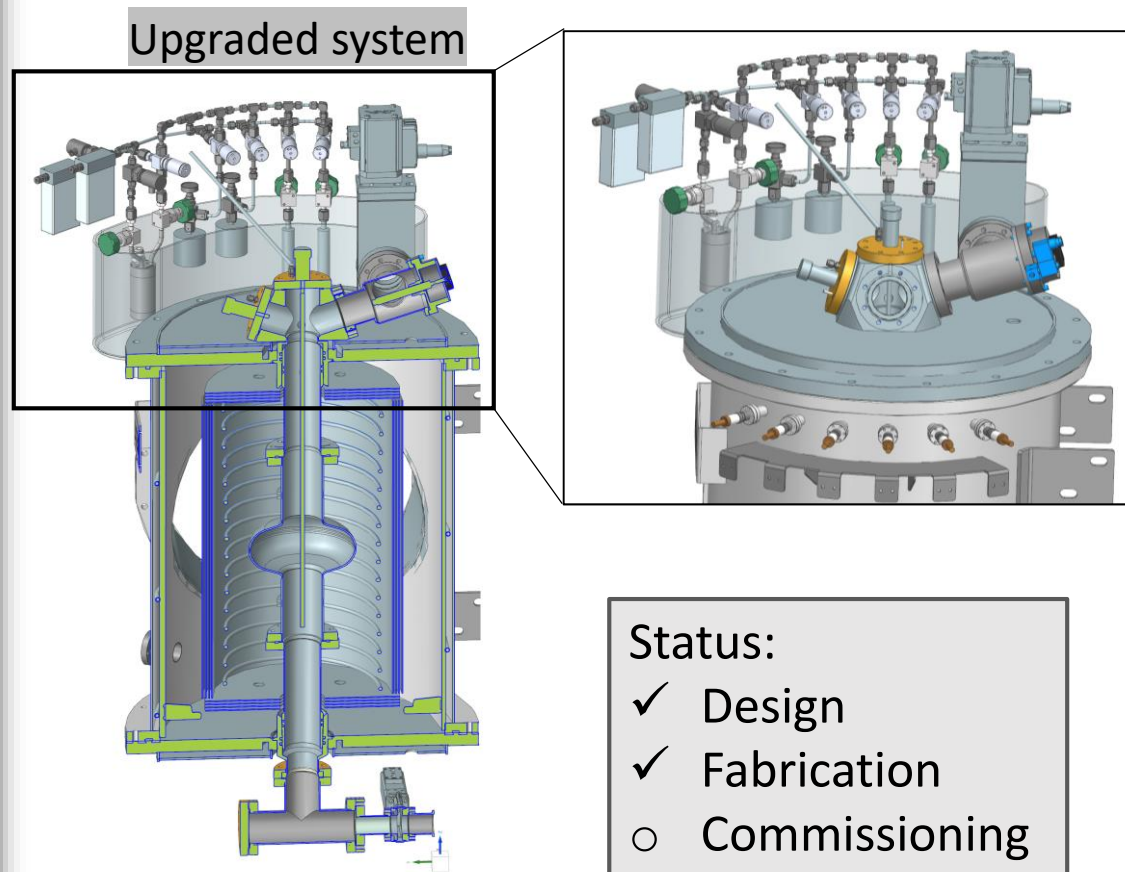


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PEALD AlN-NbTiN cavity coating – starting next year



EXTEND SINGLE-CELL FURNACE TO PEALD-SINGLE-CELL COATING SYSTEM



High versatility in one system:

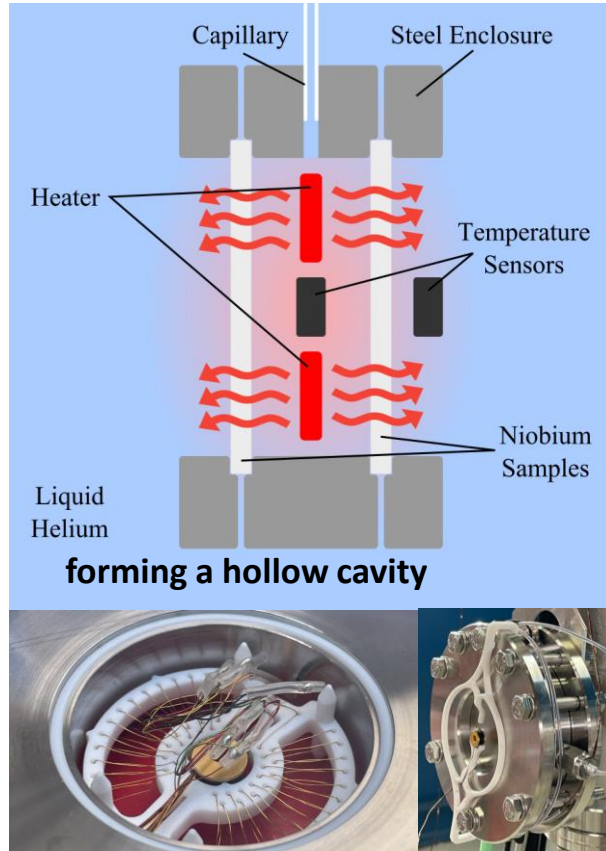
- PEALD and thermal ALD
- Capable depositing:
 - NbTiN / NbN
 - AlN
 - Al₂O₃
- In-situ annealing
 - dissolve oxide layers before coating
 - after coating

Status:

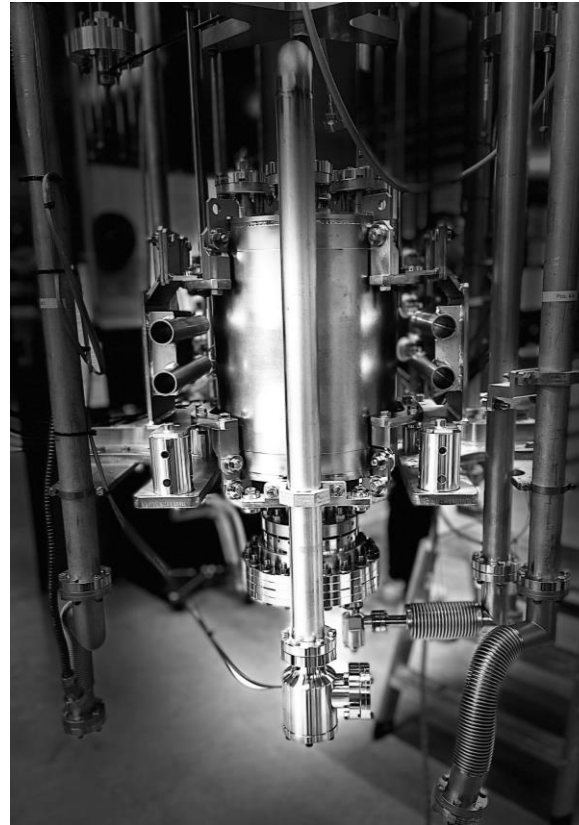
- ✓ Design
- ✓ Fabrication
- Commissioning

Related activities ongoing

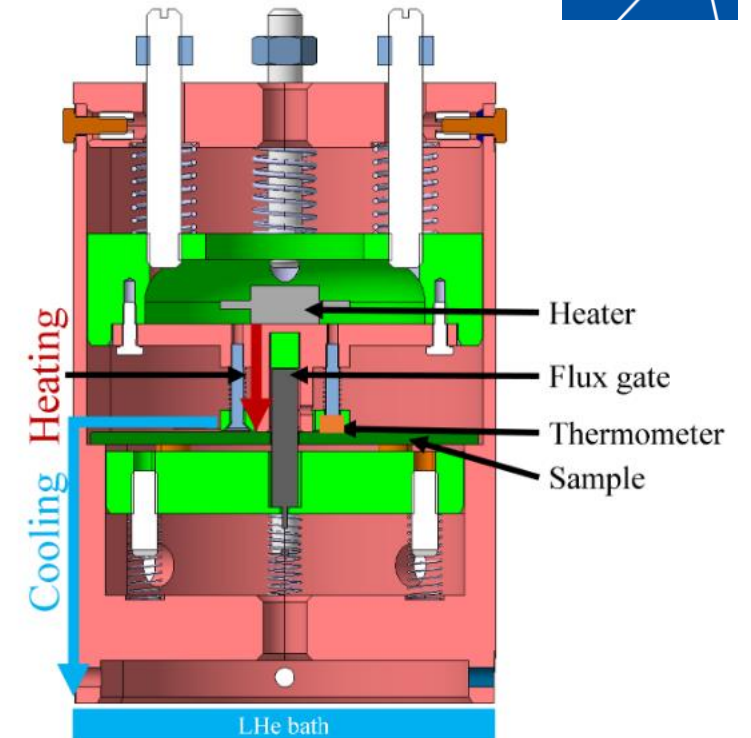
- Thermal conductivity studies at UHH/DESY



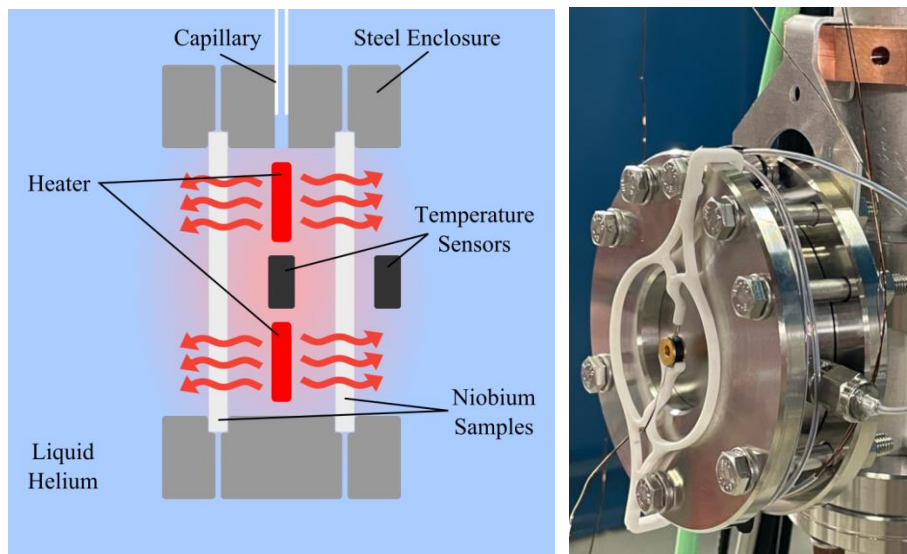
- Commissioning of the UHH Quadrupole Resonator (QPR) at DESY



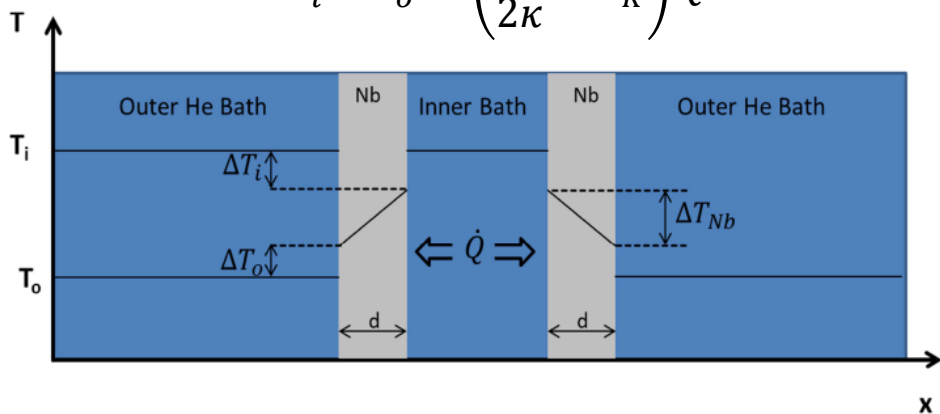
- Flux expulsion studies at CERN



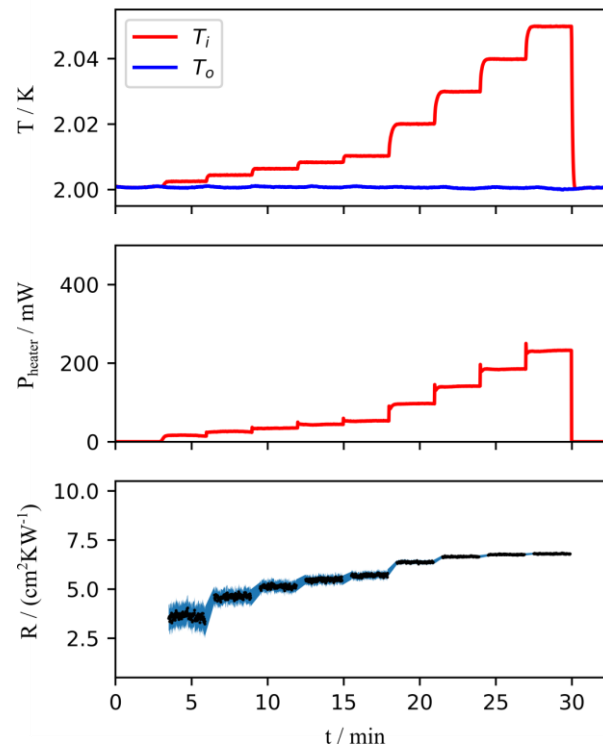
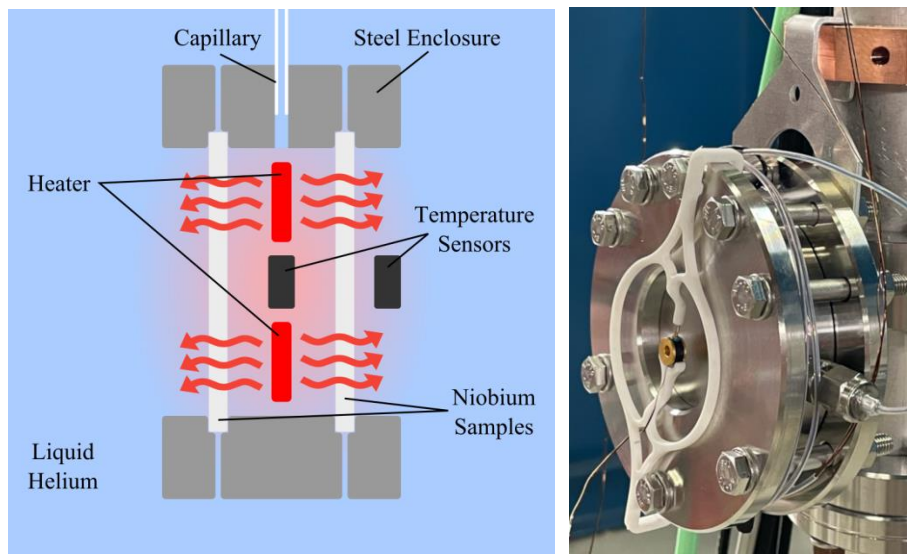
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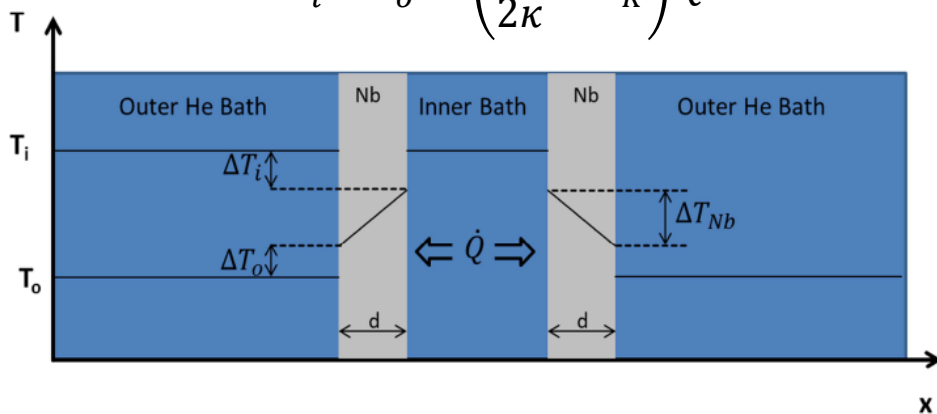
$$\Delta T = T_i - T_o = \left(\frac{d}{2\kappa} + R_K \right) \dot{Q}$$



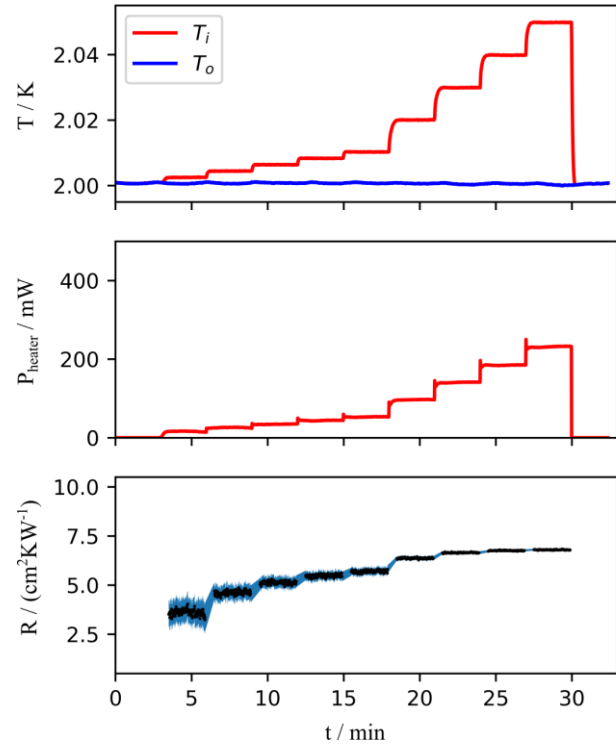
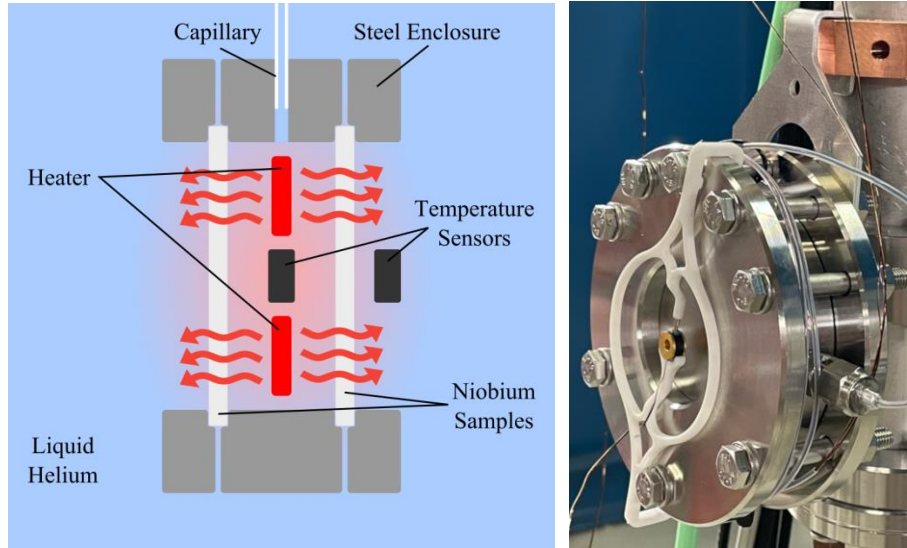
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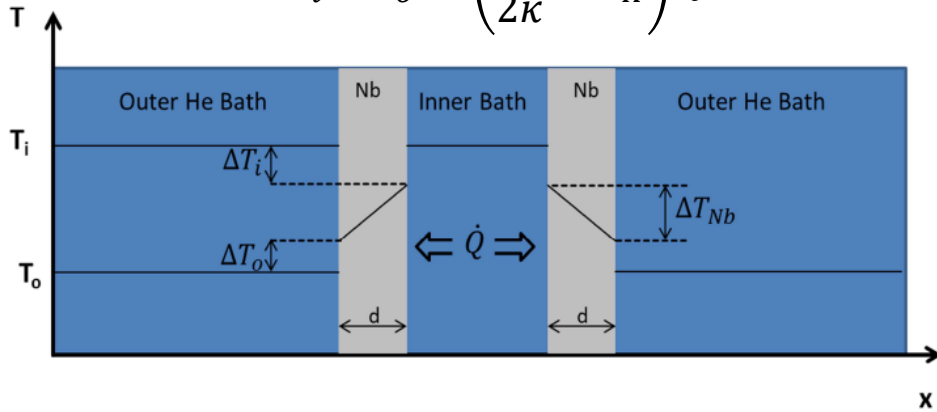
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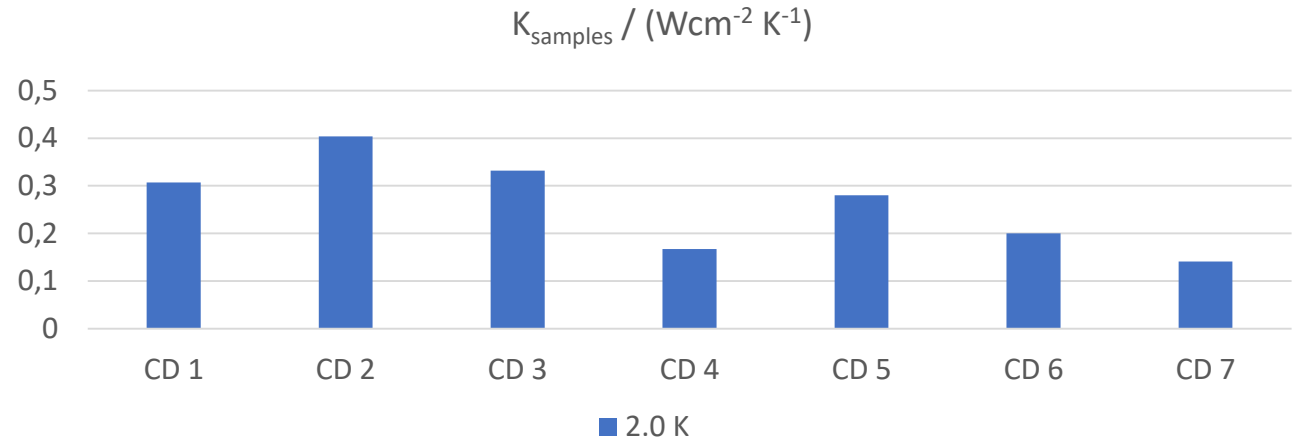
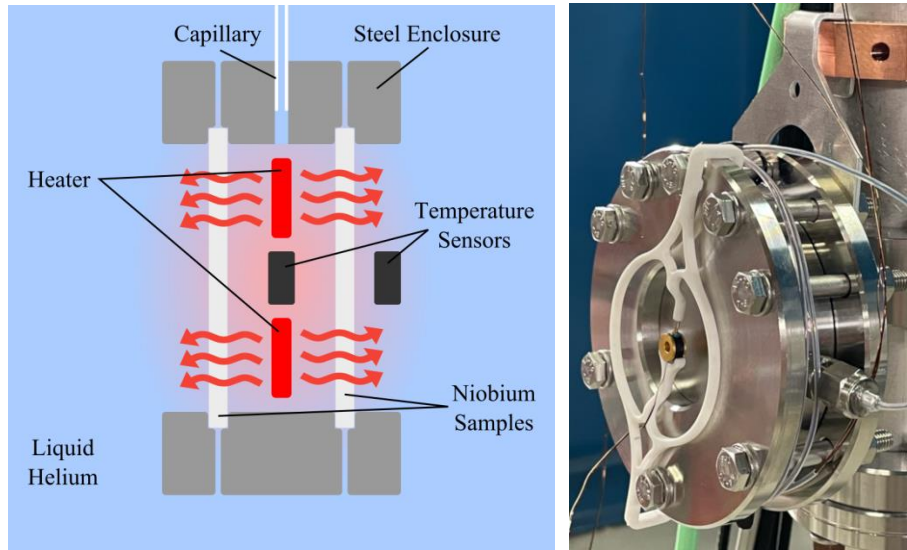


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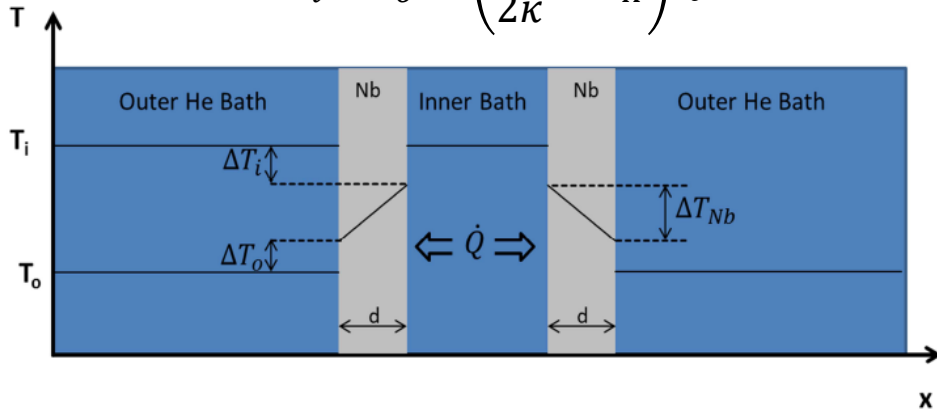


Cool Down	Sample Pair	Treatment	$K_{samples}$ ($Wcm^{-2}K^{-1}$)	3σ
1	1	as-fabricated	0.307	0.046
2	1	BCP 1	0.404	0.120
3	3	as-fabricated	0.332	0.031
4	2	BCP 1 + outgassing 1	0.167	0.016
5	3	BCP 2	0.280	0.030
6	4	BCP 2 + outgassing 2	0.200	0.019
7	3	BCP 2 + outgassing 2 + SIS	0.141	0.013

Thermal conductivity



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Take home messages

- ✓ Achieve coated cavities by thermal ALD and sustain high accelerating gradients without any performance deterioration
- ✓ SIS multilayers by PEALD and post-deposition annealing have been optimized on planar substrates – move on to cavities
- ✓ Continue material R&D and investigate potential showstoppers

Thanks to:

SRF R&D group DESY/UHH: Wolfgang Hillert, Hans Weise, Detlef Reschke, Marc Wenskat, Getnet Kacha Deyu, Cornelius Martens, Lea Steder, Rezvan Ghanbari, Lea Preece, Cem Saribal, Nicolay Krupka, Christopher Bate, Ricardo Monroy-Villa, Jonas Wolf, Mateusz Wiencek, and many more. **ALD group UHH (CHyN):** Robert Blick, Robert Zierold, Jun Peng, Carina Hedrich, Stefanie Haugg, Kristian Deneke, Malte Siegmung and more. **Collaborators:** Dirk Lützenkirchen-Hecht (U. Wuppertal), Frederic Braun (U. Wuppertal), Alick Macpherson (CERN), Daniel Turner (CERN), Tobias Junginger (U. Victoria) and more. **Organizing Committee**

Thank you for your attention

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